



1		Icc	mA	-	- 300
			mV	150	1100
			mV	300	- 600
TX_fault /LOS	(TTL)	VOH	V	2.0	- Vcc
		VOL	V	0	- 0.8
TX_disable	(TTL)	VOH	V	2.0	- Vcc
		VOL	V	0	- 0.8
		Po	dBm	-9.5	-3
		λc	nm	830	860
		EX	dB	9	
(RMS)		Δλ	nm		4
2		TJ	UI		0.284
3		RIN	dB/Hz		-120
		GE			
/		Trise/Tfall	ps		260
		-	dB		1
		Poff	dBm		-45
		λc	nm	770	870
4		S	dBm		-18
		Pin	dBm	0	
			dBm		-18
			-35		

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		dB	0.5		5
Note1.					
Note2. 1.25Gbps 7 .					
Note3. RIN					
12dB					
Note4. PRBS 2 ⁷ -1 1.25Gb/s EX=10dB BER<10 ⁻¹²					

RTXM191-552	SFP	1.25G	850nm FP	-9.5~ -3dBm	PIN	< -18dBm	-40~85℃	0.55km	DDM, RoHS